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Bib Data Sheet

SERIAL NUMBER 10/670,331	FILING DATE. 09/26/2003	CLASS 267 438	GROUP ART UNIT 2825	ATTORNEY DOCKET NO. 242984US2CIP
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## APPLICANTS

Mitsuru Kaneda, Tokyo, JAPAN;

Hideki Takahashi, Tokyo, JAPAN;

## \*\* CONTINUING DATA \*\*\*\*\*

This application is a CIP of 10/366,520 02/14/2003 ✓ ABN

## \*\* FOREIGN APPLICATIONS \*\*\*\*\*

JAPAN 2002-280666 09/26/2002 ✓

JAPAN 2003-194129 07/09/2003 ✓

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 12/22/2003

Foreign Priority claimed 35 USC 119 (a-d) conditions met	✓ yes <input type="checkbox"/> no ✓ yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance	STATE OR COUNTRY JAPAN	SHEETS DRAWING 23 ✓	TOTAL CLAIMS 26 ✓	INDEPENDENT CLAIMS 6 ✓
Verified and Acknowledged  Examiner's Signature Initials					

## ADDRESS

22850

OBLON, SPIVAK, MCCLELLAND, MAIER &amp; NEUSTADT, P.C.

1940 DUKE STREET

ALEXANDRIA, VA

22314

## TITLE

Semiconductor substrate with defects reduced or removed and method of manufacturing the same, and semiconductor device capable of bidirectionally retaining breakdown voltage and method of manufacturing the same

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